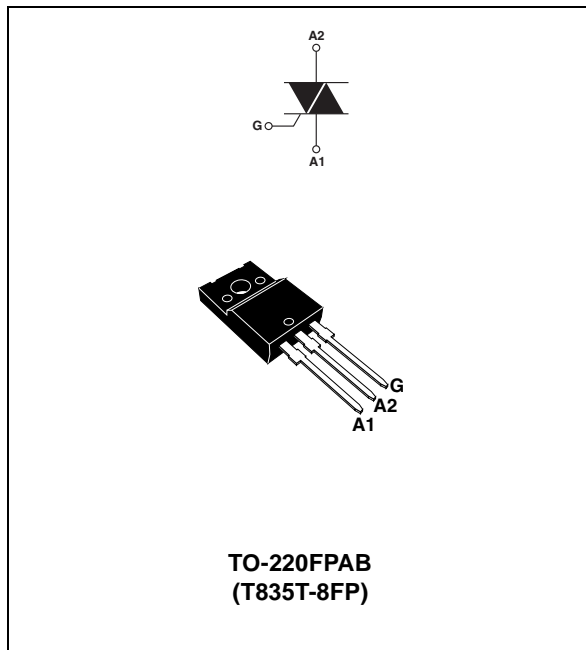


**8 A Snubberless™ Triac**

Datasheet – production data


**Table 1. Device summary**

Symbol	Value	Unit
$I_{T(rms)}$	8	A
$V_{DRM}, V_{RRM}$	800	V
$V_{DSM}, V_{RSM}$	900	V
$I_{GT}$	35	mA

**Features**

- Medium current Triac
- High static and dynamic commutation
- Three quadrants
- ECOPACK®2 compliant component
- Complies with UL standards (File ref: E81734)

**Applications**

- General purpose AC line load switching
- Motor control circuits
- Small home appliances
- Lighting
- Inrush current limiting circuits
- Overvoltage crowbar protection

**Description**

Available in through-hole full pack package, the T835T-8FP Triac can be used for the on/off or phase angle control function in general purpose AC switching where high commutation capability is required. This device can be used without a snubber circuit when the limits defined in this datasheet are respected

Provides UL certified insulation rated at 2 kV.

TM: Snubberless is a trademark of STMicroelectronics

# 1 Characteristics

**Table 2. Absolute maximum ratings ( $T_j = 25\text{ °C}$  unless otherwise stated)**

Symbol	Parameter		Value	Unit
$I_{T(rms)}$	On-state rms current (full sine wave)		$T_c = 113\text{ °C}$ 8	A
$I_{TSM}$	Non repetitive surge peak on-state current (full cycle, $T_j$ initial = $25\text{ °C}$ )	F = 50 Hz t = 20 ms	60	A
		F = 60 Hz t = 16.7 ms	63	
$I^2t$	$I^2t$ value for fusing, $T_j$ initial = $25\text{ °C}$		$t_p = 10\text{ ms}$ 24	$A^2s$
$V_{DRM}, V_{RRM}$	Repetitive surge peak off-state voltage		$T_j = 150\text{ °C}$ 600	V
			$T_j = 125\text{ °C}$ 800	
$V_{DSM}, V_{RSM}$	Non repetitive surge peak off-state voltage		$t_p = 10\text{ ms}$ 900	V
dI/dt	Critical rate of rise of on-state current $I_G = 2 \times I_{GT}, t_r \leq 100\text{ ns}$	F = 100 Hz	100	A/ $\mu s$
$I_{GM}$	Peak gate current	$t_p = 20\text{ }\mu s$ $T_j = 150\text{ °C}$	4	A
$P_{G(AV)}$	Average gate power dissipation		$T_j = 150\text{ °C}$ 1	W
$T_{stg}$ $T_j$	Storage junction temperature range		- 40 to + 150	$^{\circ}C$
	Operating junction temperature range		- 40 to + 150	
$T_L$	Maximum lead temperature for soldering during 10 s		260	$^{\circ}C$
$V_{ins}$	Insulation rms voltage, 1 minute		2	kV

**Table 3. Electrical characteristics ( $T_j = 25\text{ °C}$ , unless otherwise stated)**

Symbol	Test conditions	Quadrant		Value	Unit
$I_{GT}^{(1)}$	$V_D = 12\text{ V}, R_L = 30\text{ }\Omega$	I - II - III	Min.	1.75	mA
			Max.	35	
$V_{GT}$	$V_D = 12\text{ V}, R_L = 30\text{ }\Omega$	I - II - III	Max.	1.3	V
$V_{GD}$	$V_D = V_{DRM}, R_L = 3.3\text{ k}\Omega, T_j = 150\text{ °C}$	I - II - III	Min.	0.2	V
$I_H^{(1)}$	$I_T = 500\text{ mA}$		Max.	40	mA
$I_L$	$I_G = 1.2 I_{GT}$	I - III	Max.	60	mA
		II	Max.	65	mA
dV/dt <sup>(1)</sup>	$V_D = 536\text{ V}, \text{ gate open}$	$T_j = 125\text{ °C}$	Min.	2000	V/ $\mu s$
	$V_D = 402\text{ V}, \text{ gate open}$	$T_j = 150\text{ °C}$		1000	V/ $\mu s$
(dI/dt) <sub>c</sub> <sup>(1)</sup>	Without snubber (dV/dt) <sub>c</sub> $\geq 20\text{ V}/\mu s$		Min.	$T_j = 125\text{ °C}$ 8	A/ms
				$T_j = 150\text{ °C}$ 4	

1. For both polarities of A2 referenced to A1

Table 4. Static Characteristics

Symbol	Test conditions		Value	Unit	
$V_T^{(1)}$	$I_{TM} = 11.3 \text{ A}$ , $t_p = 380 \mu\text{s}$	$T_j = 25 \text{ }^\circ\text{C}$	Max.	1.55	V
$V_{i0}^{(1)}$	Threshold voltage	$T_j = 150 \text{ }^\circ\text{C}$	Max.	0.85	V
$R_d^{(1)}$	Dynamic resistance	$T_j = 150 \text{ }^\circ\text{C}$	Max.	57	m $\Omega$
$I_{DRM}$ $I_{RRM}$	$V_{DRM} = V_{RRM} = 800 \text{ V}$	$T_j = 25 \text{ }^\circ\text{C}$	Max.	5	$\mu\text{A}$
		$T_j = 125 \text{ }^\circ\text{C}$		0.8	mA
	$V_{DRM} = V_{RRM} = 600 \text{ V}$	$T_j = 150 \text{ }^\circ\text{C}$	Max.	2.4	

1. For both polarities of A2 referenced to A1

Table 5. Thermal resistance

Symbol	Parameter	Value	Unit
$R_{th(j-c)}$	Junction to case (AC)	3.8	$^\circ\text{C/W}$
$R_{th(j-a)}$	Junction to ambient	60	$^\circ\text{C/W}$

Figure 1. Maximum power dissipation versus on-state rms current (full cycle)

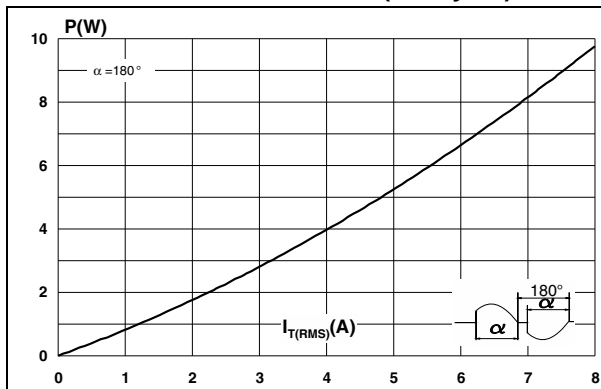


Figure 2. On-state rms current versus case temperature (full cycle)

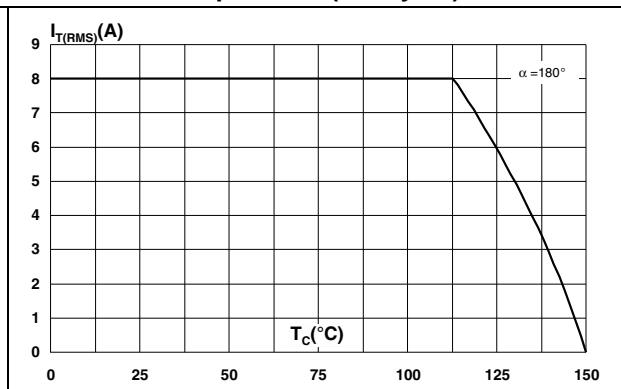


Figure 3. On-state rms current versus ambient temperature (free air convection)

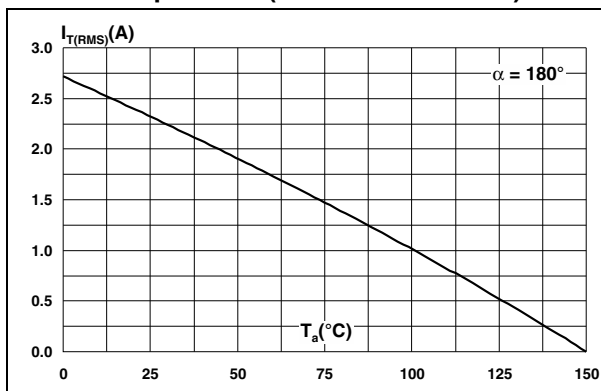


Figure 4. Relative variation of thermal impedance versus pulse duration

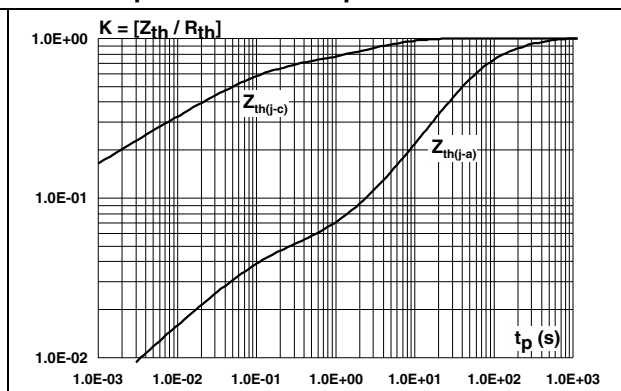


Figure 5. On-state characteristics (maximum values)

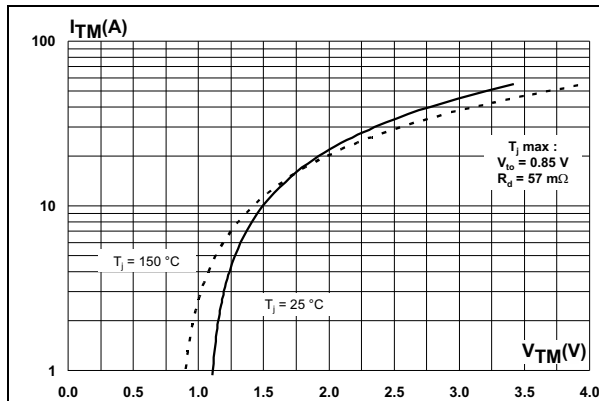


Figure 6. Surge peak on-state current versus number of cycles

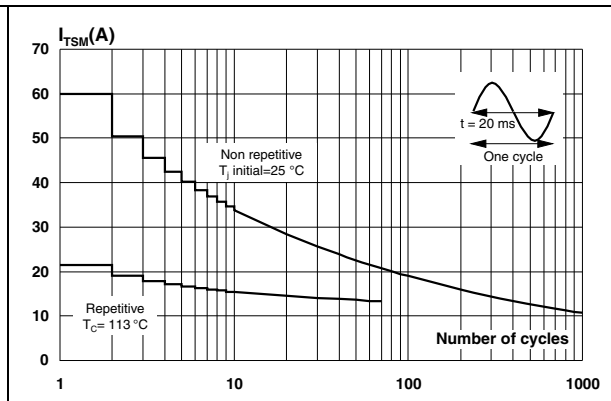


Figure 7. Non repetitive surge peak on-state current and corresponding values of  $I^2t$

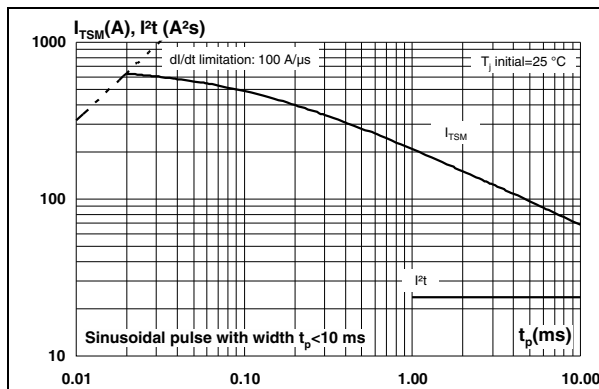


Figure 8. Relative variation of gate trigger current and gate voltage versus junction temperature (typical values)

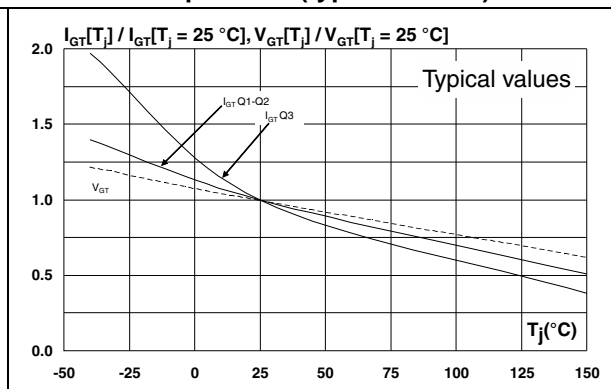


Figure 9. Relative variation of static dV/dt immunity versus junction temperature (typical values)

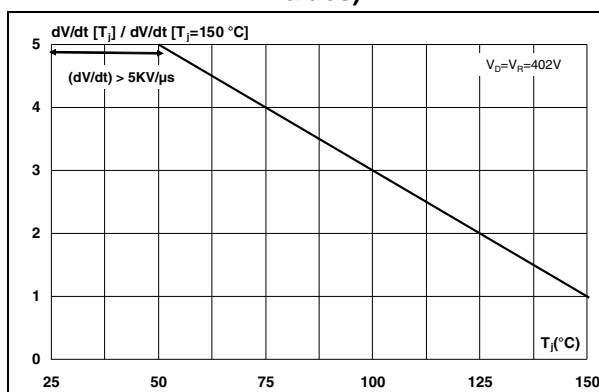


Figure 10. Relative variation of holding and latching current versus junction temperature (typical values)

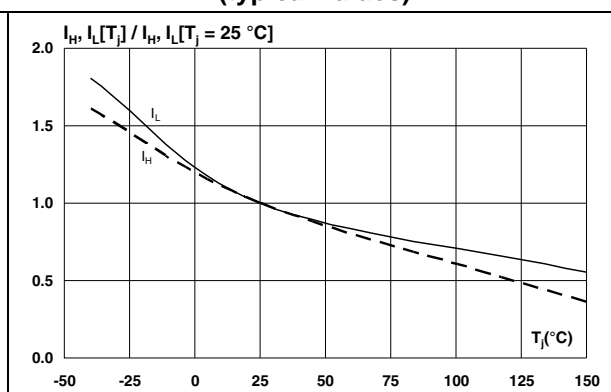


Figure 11. Relative variation of critical rate of decrease of main current  $(di/dt)_c$  versus reapplied  $(dV/dt)_c$  (typical values)

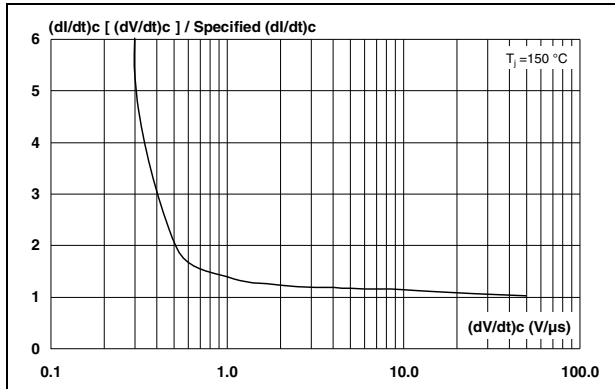


Figure 12. Relative variation of critical rate of decrease of main current  $(di/dt)_c$  versus junction temperature (typical values)

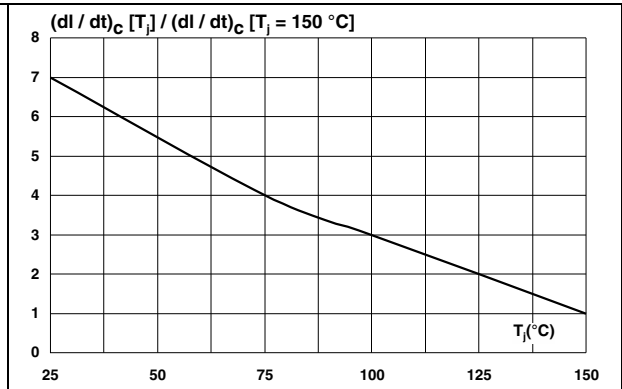
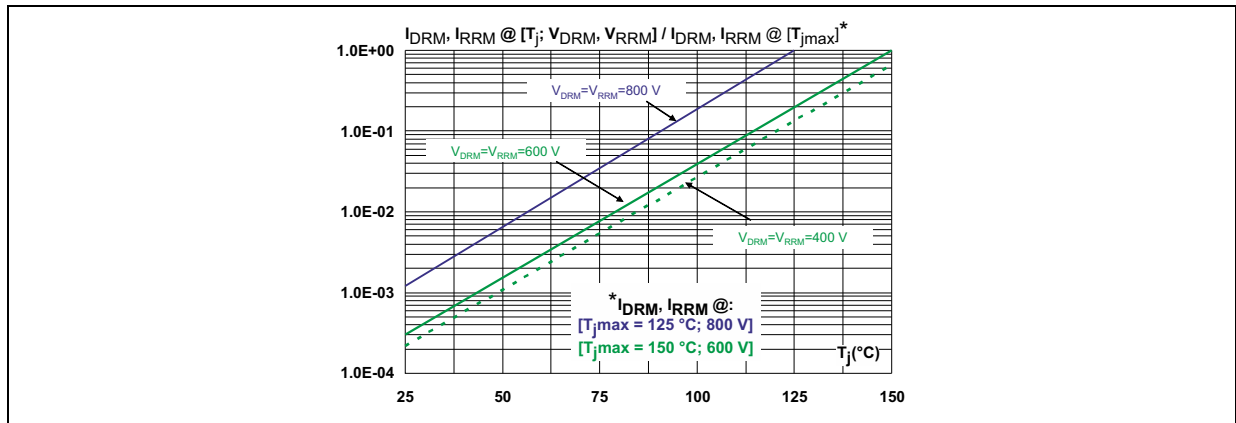


Figure 13. Relative variation of leakage current versus junction temperature for different values of blocking voltage (typical values)



## 2 Package information

- Epoxy meets UL94, V0
- Lead-free package
- Recommended torque: 0.4 to 0.6 N·m

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com). ECOPACK® is an ST trademark.

Figure 14. TO-220FPAB dimension definitions

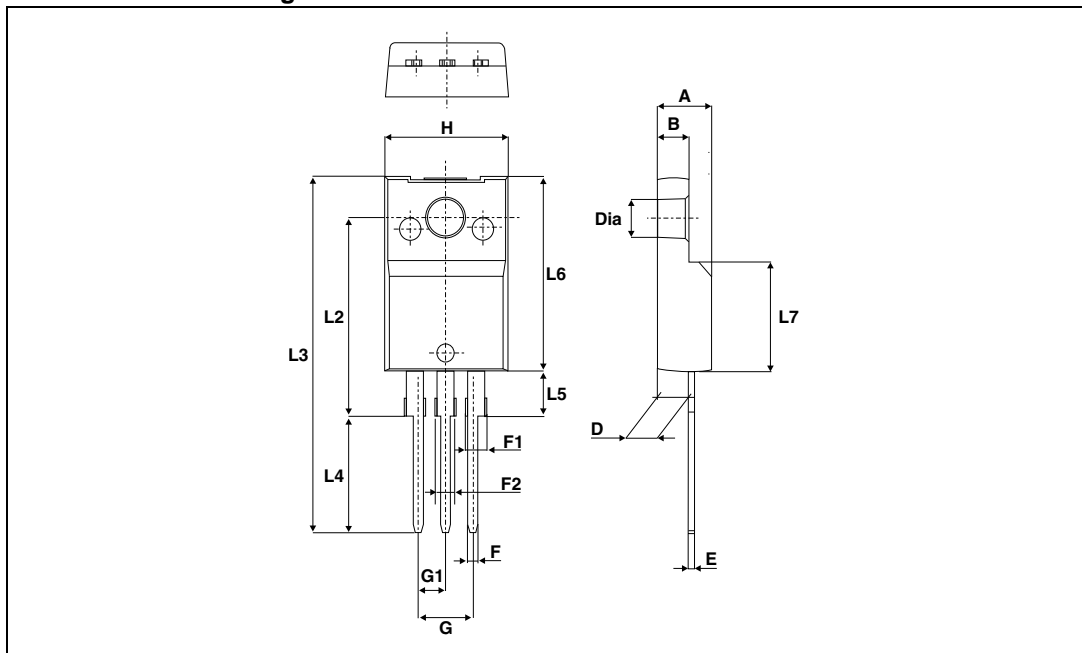


Table 6. TO-220FPAB dimension values

Ref.	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.4	4.6	0.173	0.181
B	2.5	2.7	0.098	0.106
D	2.5	2.75	0.098	0.108
E	0.45	0.70	0.018	0.027
F	0.75	1	0.030	0.039
F1	1.15	1.70	0.045	0.067
F2	1.15	1.70	0.045	0.067
G	4.95	5.20	0.195	0.205
G1	2.4	2.7	0.094	0.106
H	10	10.4	0.393	0.409
L2	16 Typ.		0.63 Typ.	
L3	28.6	30.6	1.126	1.205
L4	9.8	10.6	0.386	0.417
L5	2.9	3.6	0.114	0.142
L6	15.9	16.4	0.626	0.646
L7	9.00	9.30	0.354	0.366
Dia.	3.00	3.20	0.118	0.126

### 3 Ordering information

Figure 15. Ordering information scheme

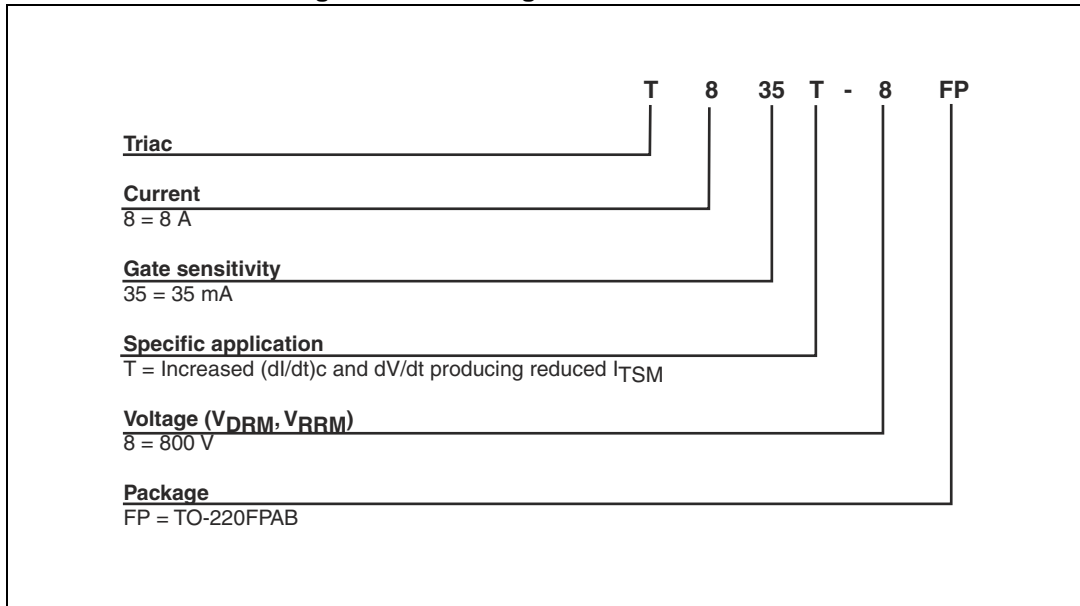


Table 7. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
T835T-8FP	T835T-8FP	TO-220FPAB	2.0 g	50	Tube

### 4 Revision history

Table 8. Document revision history

Date	Revision	Changes
05-Mar-2013	1	Initial release.
14-Jan-2015	2	Updated <a href="#">Features</a> , <a href="#">Table 2</a> and <a href="#">Table 5</a> .



**IMPORTANT NOTICE – PLEASE READ CAREFULLY**

STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, enhancements, modifications, and improvements to ST products and/or to this document at any time without notice. Purchasers should obtain the latest relevant information on ST products before placing orders. ST products are sold pursuant to ST's terms and conditions of sale in place at the time of order acknowledgement.

Purchasers are solely responsible for the choice, selection, and use of ST products and ST assumes no liability for application assistance or the design of Purchasers' products.

No license, express or implied, to any intellectual property right is granted by ST herein.

Resale of ST products with provisions different from the information set forth herein shall void any warranty granted by ST for such product.

ST and the ST logo are trademarks of ST. All other product or service names are the property of their respective owners.

Information in this document supersedes and replaces information previously supplied in any prior versions of this document.

© 2015 STMicroelectronics – All rights reserved

Компания «Life Electronics» занимается поставками электронных компонентов импортного и отечественного производства от производителей и со складов крупных дистрибьюторов Европы, Америки и Азии.

С конца 2013 года компания активно расширяет линейку поставок компонентов по направлению коаксиальный кабель, кварцевые генераторы и конденсаторы (керамические, пленочные, электролитические), за счёт заключения дистрибьюторских договоров

Мы предлагаем:

- Конкурентоспособные цены и скидки постоянным клиентам.
- Специальные условия для постоянных клиентов.
- Подбор аналогов.
- Поставку компонентов в любых объемах, удовлетворяющих вашим потребностям.
- Приемлемые сроки поставки, возможна ускоренная поставка.
- Доставку товара в любую точку России и стран СНГ.
- Комплексную поставку.
- Работу по проектам и поставку образцов.
- Формирование склада под заказчика.
- Сертификаты соответствия на поставляемую продукцию (по желанию клиента).
- Тестирование поставляемой продукции.
- Поставку компонентов, требующих военную и космическую приемку.
- Входной контроль качества.
- Наличие сертификата ISO.

В составе нашей компании организован Конструкторский отдел, призванный помогать разработчикам, и инженерам.

Конструкторский отдел помогает осуществить:

- Регистрацию проекта у производителя компонентов.
- Техническую поддержку проекта.
- Защиту от снятия компонента с производства.
- Оценку стоимости проекта по компонентам.
- Изготовление тестовой платы монтаж и пусконаладочные работы.



Тел: +7 (812) 336 43 04 (многоканальный)

Email: [org@lifeelectronics.ru](mailto:org@lifeelectronics.ru)